600V N-CHANNEL ENHANCEMENT MODE MOSFET

MAIN CHARACTERISTICS

I_D	
V_{DSS}	
R_{DSON}-typ(@V_{GS}=10V)	(Typ:0.325 Ω)

FEATURES

	TO-220F	0.06oz(1.74g)	50pcs/tube	1000PCS/Box 5000PCS/Carton

Marking Diagram

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